

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

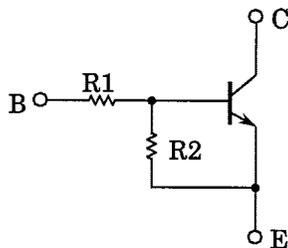
## RN1107, RN1108, RN1109

Switching, Inverter Circuit, Interface Circuit  
And Driver Circuit Applications

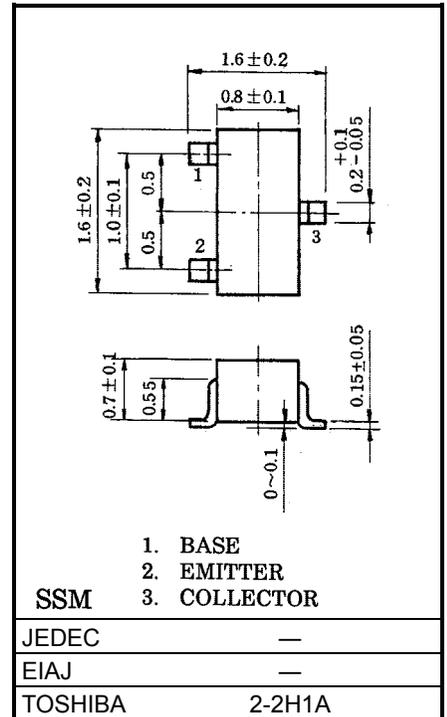
Unit: mm

- With built-in bias resistors.
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2107~2109

### Equivalent Circuit and Bias Resistor Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN1107	10	47
RN1108	22	47
RN1109	47	22



Weight: 2.4mg

### Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
Collector-base voltage	RN1107~1109	$V_{CB0}$	50	V
Collector-emitter voltage	RN1107~1109	$V_{CEO}$	50	V
Emitter-base voltage	RN1107	$V_{EBO}$	6	V
	RN1108		7	
	RN1109		15	
Collector current	RN1107~1109	$I_c$	100	mA
Collector power dissipation	RN1107~1109	$P_c$	100	mW
Junction temperature	RN1107~1109	$T_j$	150	°C
Storage temperature range	RN1107~1109	$T_{stg}$	-55~150	°C

## Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	RN1107~1109	$I_{CBO}$	—	$V_{CB} = 50V, I_E = 0$	—	—	100	nA
		$I_{CEO}$	—	$V_{CE} = 50V, I_B = 0$	—	—	500	nA
Emitter cut-off current	RN1107	$I_{EBO}$	—	$V_{EB} = 6V, I_C = 0$	0.081	—	0.15	mA
	RN1108		—	$V_{EB} = 7V, I_C = 0$	0.078	—	0.145	
	RN1109		—	$V_{EB} = 15V, I_C = 0$	0.167	—	0.311	
DC current gain	RN1107	$h_{FE}$	—	$V_{CE} = 5V, I_C = 10mA$	80	—	—	—
	RN1108		—		80	—	—	
	RN1109		—		70	—	—	
Collector-emitter saturation voltage	RN1107~1109	$V_{CE(sat)}$	—	$I_C = 5mA, I_B = 0.25mA$	—	0.1	0.3	V
Input voltage (ON)	RN1107	$V_{I(ON)}$	—	$V_{CE} = 0.2V, I_C = 5mA$	0.7	—	1.8	V
	RN1108		—		1.0	—	2.6	
	RN1109		—		2.2	—	5.8	
Input voltage (OFF)	RN1107	$V_{I(OFF)}$	—	$V_{CE} = 5V, I_C = 0.1mA$	0.5	—	1.0	V
	RN1108		—		0.6	—	1.16	
	RN1109		—		1.5	—	2.6	
Translation frequency	RN1107~1109	$f_T$	—	$V_{CE} = 10V, I_C = 5mA$	—	250	—	MHz
Collector output capacitance	RN1107~1109	$C_{ob}$	—	$V_{CB} = 10V, I_E = 0, f = 1MHz$	—	3	6	pF
Input Resistor	RN1107	R1	—	—	7	10	13	kΩ
	RN1108		—		15.4	22	28.6	
	RN1109		—		32.9	47	61.1	
Resistor Ratio	RN1107	R1/R2	—	—	0.191	0.213	0.232	—
	RN1108		—		0.421	0.468	0.515	
	RN1109		—		1.92	2.14	2.35	

